



DMN6040SK3Q

Product Summary

| BV _{DSS} | Rds(on) max | Ι _D T _C = +25°C |
|-------------------|-------------------------------|--|
| 60V | 40mΩ @ V _{GS} = 10V | 20A |
| 000 | 58mΩ @ V _{GS} = 4.5V | 16A |

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Backlighting

Features

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

60V N-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

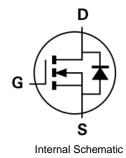
- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



TO252 (DPAK)

G S Top View

D



Ordering Information (Note 5)

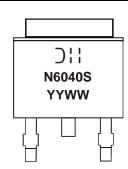
| | Part Number | Case | Packaging | | | |
|----------------|--|--------------|-------------------|--|--|--|
| DMN6040SK3Q-13 | | TO252 (DPAK) | 2,500/Tape & Reel | | | |
| Notes: | Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. | | | | | |

No purposely added lead. Fully ED Directive 2002/95/EC (ROFS), 2017/05/ED (ROFS 2) & 2015/05/ED (ROFS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



):: =Manufacturer's Marking
N6040S = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 18 = 2018)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|--|------------------|---|------------------|----------|------|
| Drain-Source Voltage | V _{DSS} | 60 | V | | |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6) V_{GS} = 10V | Steady State | $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$ | ID | 20 13 | А |
| Maximum Body Diode Forward Current (Note 6) | | | Is | 4 | A |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | | I _{DM} | 30 | A |
| Avalanche Current (Note 7) | | | I _{AS} | 14.2 | A |
| Avalanche Energy (Note 7) | | | E _{AS} | 10 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|-----------------------------------|-------------|------|---|
| Tatal Dower Dissinction (Nate 6) | T _C = +25°C | D | 42 | W |
| Total Power Dissipation (Note 6) | T _C = +100°C | PD | 17 | |
| Thermal Resistance, Junction to Ambient (Note 6) | R _{0JA} | 44 | 80AM | |
| Thermal Resistance, Junction to Case (Note 6) | R _{0JC} | 3 | °C/W | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

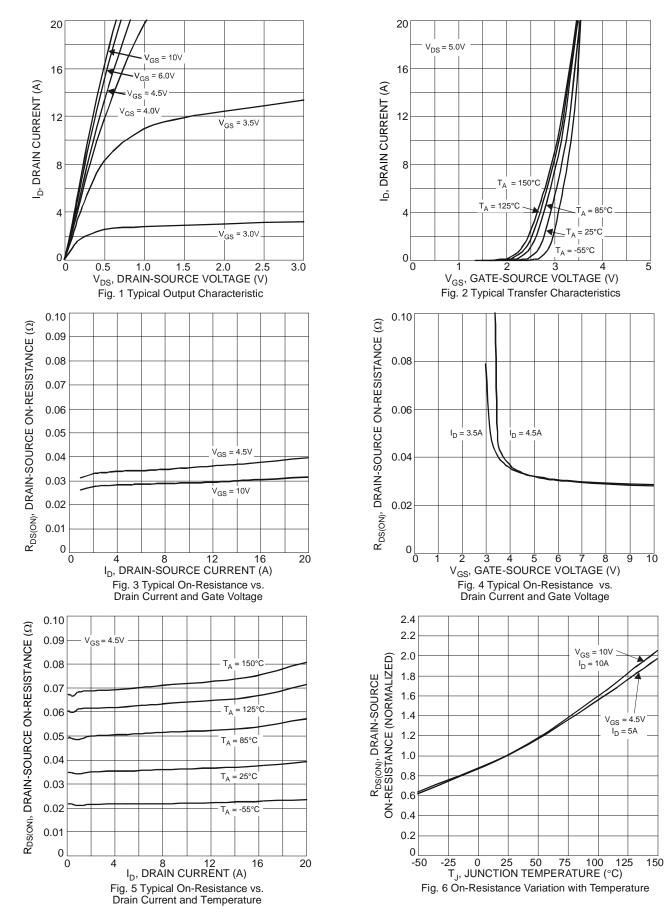
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|------|-------|--|--|
| OFF CHARACTERISTICS (Note 8) | •,• | | - 71- | 1 | 1 | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 60 | | | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | | | 1 | μA | $V_{DS} = 60V, V_{GS} = 0V$ | |
| Gate-Source Leakage | IGSS | _ | | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | | 3 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Б | _ | 30 | 40 | - mΩ | $V_{GS} = 10V, I_D = 20A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 35 | 58 | 11122 | $V_{GS} = 4.5V, I_D = 12A$ | |
| Diode Forward Voltage | V _{SD} | _ | 0.7 | 1.2 | V | $V_{GS} = 0V, I_{S} = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | Ciss | | 1,287 | | | $V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz | |
| Output Capacitance | Coss | — | 57 | — | pF | | |
| Reverse Transfer Capacitance | C _{rss} | _ | 44 | — | | | |
| Gate Resistance | R _G | _ | 1.2 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 22.4 | _ | | | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 10.4 | — | nC | $V_{DS} = 30V, I_D = 4.3A$ | |
| Gate-Source Charge | Q _{gs} | _ | 4.9 | _ | nc | | |
| Gate-Drain Charge | Q _{gd} | _ | 3.0 | _ | | | |
| Turn-On Delay Time | t _{D(ON)} | _ | 6.6 | _ | | | |
| Turn-On Rise Time | t _R | _ | 8.1 | _ | | $\label{eq:VGS} \begin{array}{l} V_{GS} = 10V, V_{DD} = 30V, R_{G} = 6\Omega, \\ I_{D} = 4.3A \end{array}$ | |
| Turn-Off Delay Time | t _{D(OFF)} | | 20.1 | | ns | | |
| Turn-Off Fall Time | tF | | 4.0 | | | | |
| Body Diode Reverse Recovery Time | t _{RR} | | 18 | | ns | I _S = 4.3A, dI/dt = 100A/µs | |
| Body Diode Reverse Recovery Charge | Q _{RR} | | 11.9 | | nC | I _S = 4.3A, dl/dt = 100A/µs | |

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout. 7. UIS in production with L = 0.1mH, T_J = +25°C. Notes:

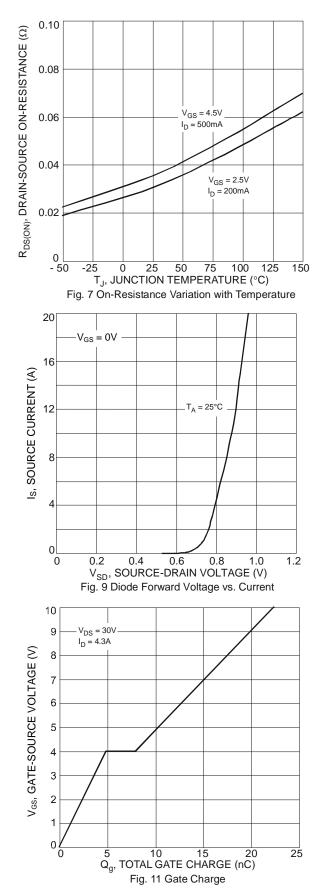
8. Short duration pulse test used to minimize self-heating effect.

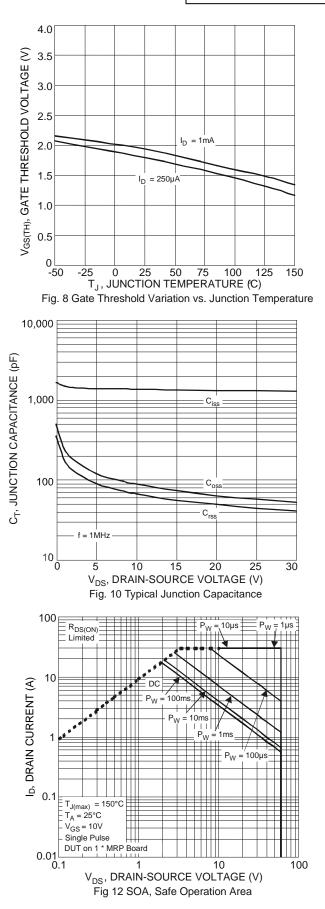
9. Guaranteed by design. Not subject to product testing.







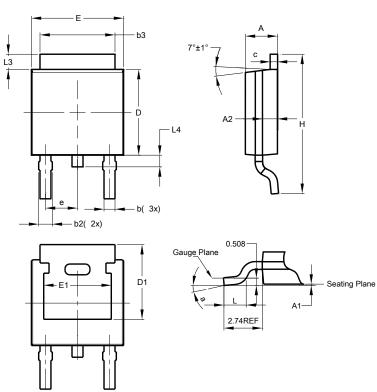






Package Outline Dimensions

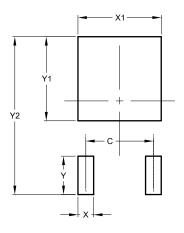
Please see http://www.diodes.com/package-outlines.html for the latest version.



| TO252 (DPAK) | | | | | | |
|--------------|----------------------|-------|-------|--|--|--|
| Dim | Min | Max | ́Тур | | | |
| Α | 2.19 | 2.39 | 2.29 | | | |
| A1 | 0.00 | 0.13 | 0.08 | | | |
| A2 | 0.97 | 1.17 | 1.07 | | | |
| b | 0.64 | 0.88 | 0.783 | | | |
| b2 | 0.76 | 1.14 | 0.95 | | | |
| b3 | 5.21 | 5.46 | 5.33 | | | |
| С | 0.45 | 0.58 | 0.531 | | | |
| D | 6.00 | 6.20 | 6.10 | | | |
| D1 | 5.21 | - | - | | | |
| е | - | - | 2.286 | | | |
| Е | 6.45 | 6.70 | 6.58 | | | |
| E1 | 4.32 | - | - | | | |
| Η | 9.40 | 10.41 | 9.91 | | | |
| L | 1.40 | 1.78 | 1.59 | | | |
| L3 | 0.88 | 1.27 | 1.08 | | | |
| L4 | 0.64 | 1.02 | 0.83 | | | |
| а | 0° | 10° | - | | | |
| All | All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)

| Dimensions | Value (in mm) |
|------------|---------------|
| С | 4.572 |
| Х | 1.060 |
| X1 | 5.632 |
| Y | 2.600 |
| Y1 | 5.700 |
| Y2 | 10.700 |

TO252 (DPAK)



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